Features

- Built-In Bias Resistors Enable the Configuration of an Inverter Circuit Without Connecting External Input Resistors
- The Bias Resistors Consist of Thin-Film Resistors With Complete Isolation to Allow Negative Biasing of the Input. They Also Have the Advantage of Almost Completely Eliminating Parasitic Effects
- Only the On/Off Conditions Need to Be Set For Operation, Making Device Design Easy
- Halogen Free. “Green” Device (Note 1)
- Moisture Sensitivity Level 1
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant.See Ordering Information)

PNP
Digital Transistor

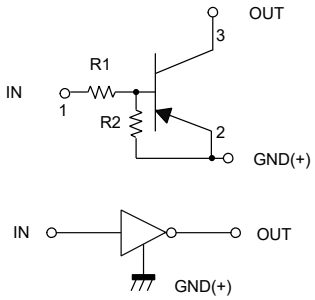
Maximum Ratings @ 25°C Unless Otherwise Specified

Parameter	Symbol	Min	Typ	Max	Unit
Supply Voltage	V_{CC}	---	-50	---	V
Input Voltage	V_{IN}	-30	---	10	V
Output Current	I_O	---	-100	---	mA
	$I_{C(Max)}$	---	-100	---	mA
Power Dissipation	P_D	---	150	---	mW
Junction Temperature	T_J	---	---	150	°C
Storage Temperature	T_{stg}	-55	---	150	°C

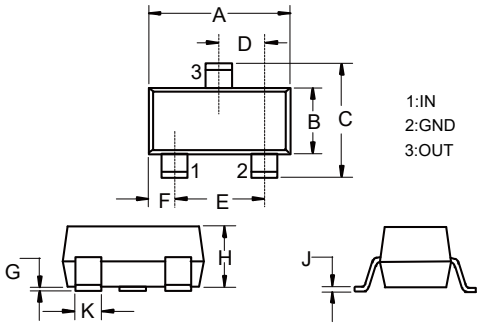
Note: 1. Halogen free "Green” products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

Device Marking：13

Internal Structure



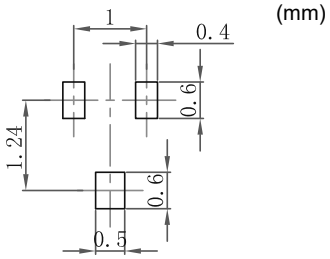
SOT-523



DIMENSIONS					
DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	0.059	0.067	1.50	1.70	
B	0.030	0.033	0.75	0.85	
C	0.057	0.069	1.45	1.75	
D	0.020		0.50		TYP.
E	0.035	0.043	0.90	1.10	
G	0.000	0.004	0.00	0.10	
H	0.024	0.031	0.60	0.80	
J	0.004	0.008	0.10	0.20	
K	0.006	0.014	0.15	0.35	

Suggested Solder Pad Layout

(mm)



Electrical Characteristics @ 25°C Unless Otherwise Specified

Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Input Voltage	$V_{I(off)}$	-0.5	---	---	V	V_{CC}=-5V, I_O=-100μA
	$V_{I(on)}$	---	---	-3.0	V	V_O=-0.3V, I_O=-20mA
Output Voltage	$V_{O(on)}$	---	---	-0.3	V	I_O=-10mA,I_I=-0.5mA
Input Current	I_I	---	---	-1.8	mA	V_I=-5V
Output Current	$I_{O(off)}$	---	---	-0.5	μA	V_{CC}=-50V, V_I=0
DC Current Gain	G_I	30	---	---		V_O=-5V, I_O=-10mA
Input Resistance	R_1	3.29	4.7	6.11	KΩ	
Resistance Ratio	R_2/R_1	0.8	1.0	1.2		
Transition Frequency	f_T	---	250	---	MHz	V_{CE}=-10V, I_E=5mA, f=100MHz

Curve Characteristics

Fig. 1 - DC Current Gain Characteristics

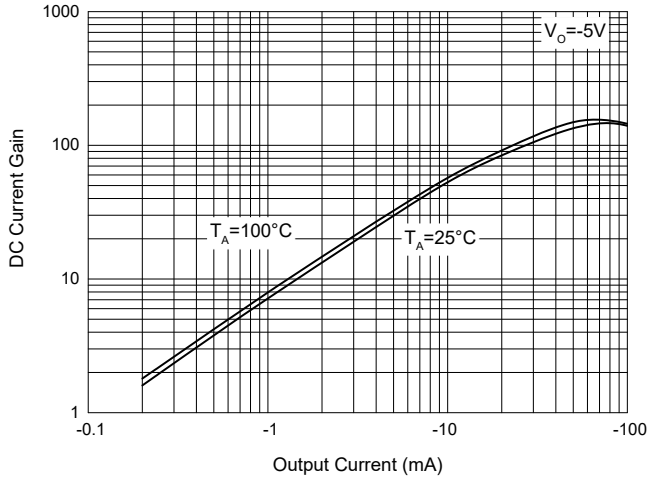


Fig. 2 - Input Voltage (on) Characteristics

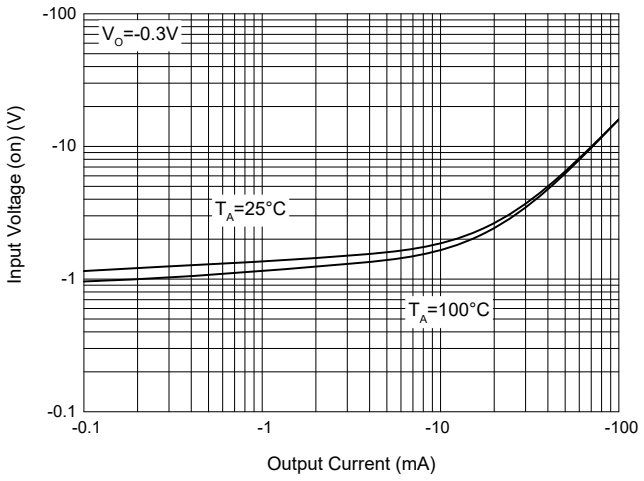


Fig. 3 - Input Voltage (off) Characteristics

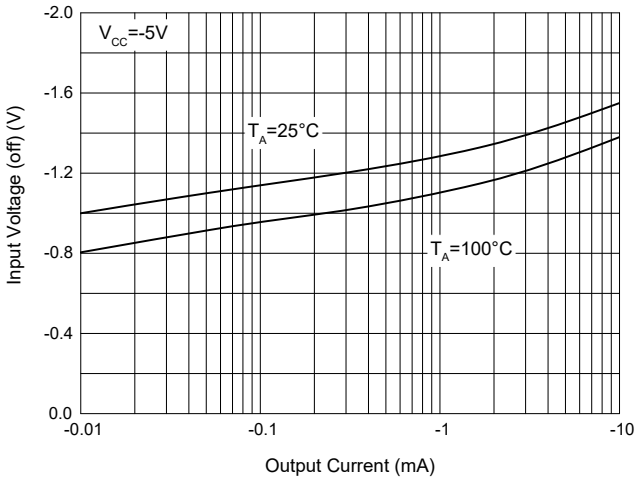


Fig. 4 - Output Voltage Characteristics

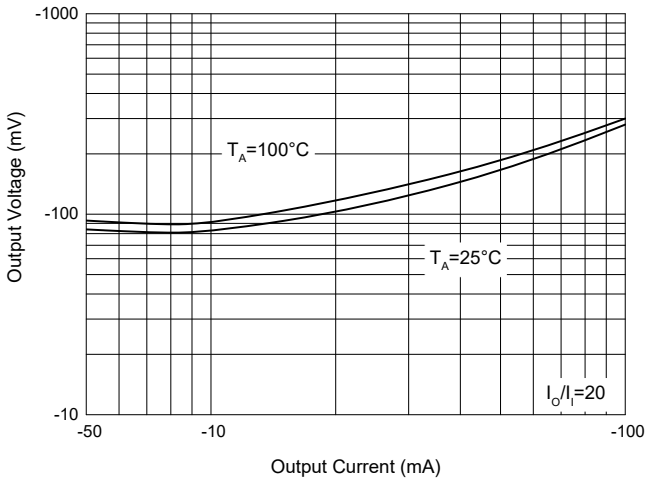


Fig. 5 - Power Derating Curve